

II. Schottky Rectifier

1.0A Surface Mount Schottky Rectifier FM102~FM110

(Package: SOD-123)

<p><u>FEATURES</u></p> <ul style="list-style-type: none"> • Silicon epitaxial planar chip, metal-silicon junction • Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance • Ultra high speed switching • Low power loss, high efficiency • Low forward voltage drop, high current capability • Guardring for overvoltage protection • The plastic material carries UL recognition 94V-0 <p><u>MECHANICAL DATA</u></p> <ul style="list-style-type: none"> • Case : Molded plastic, SOD-123 / Mini SMA • Terminals : Plated terminals, solderable per MIL-STD-750, Method 2026 • Mounting position : Any • Polarity : Color band denotes cathode • Weight : approx. 0.027 grams 	<p>Case: SOD-123 Dimensions in inches and (millimeters)</p>
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Ratings & Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristics	Symbol	FM102	FM103	FM104	FM105	FM106	FM108	FM110	Units
Component Marking		12	13	14	15	16	18	110	
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	Volts
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current See Fig.1	I_o	1.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load. (JEDEC Method)	I_{FSM}	30							Amps
Maximum forward voltage at 1.0 A DC	V_F	0.50		0.70		0.85		Volts	
Maximum DC reverse current at rated DC blocking voltage	I_R	0.5 10							mA
Typical junction capacitance (Note 1)	C_j	120							PF
Typical thermal resistance (Note 2)	R_{th-JA}	98							°C/W
Operating temperature range	T_J	-55 to +125			-55 to +150				°C
Storage temperature range	T_{stg}	-65 to +175							°C

Notes:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
2. Thermal resistance junction to ambient.

Ratings and Characteristic Curves of FM102~FM110

FIG.1 TYPICAL FORWARD CURRENT DERATING CURVE

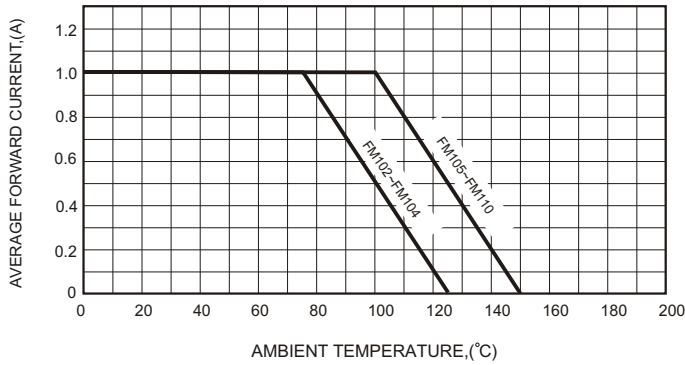


FIG.2 TYPICAL FORWARD CHARACTERISTICS

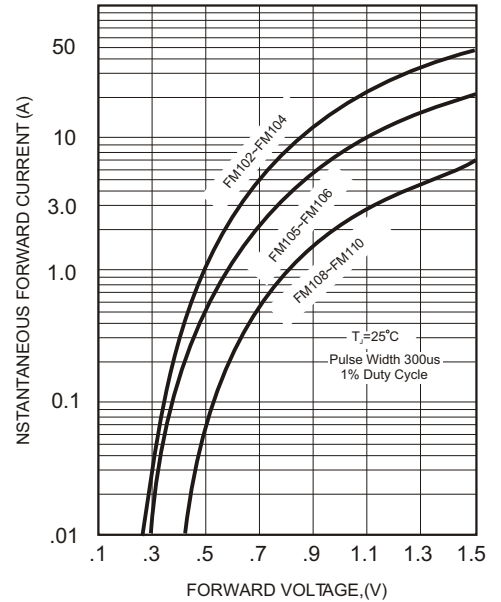


FIG.3 MAXIMUM NON REPETITIVE FORWARD SURGE CURRENT

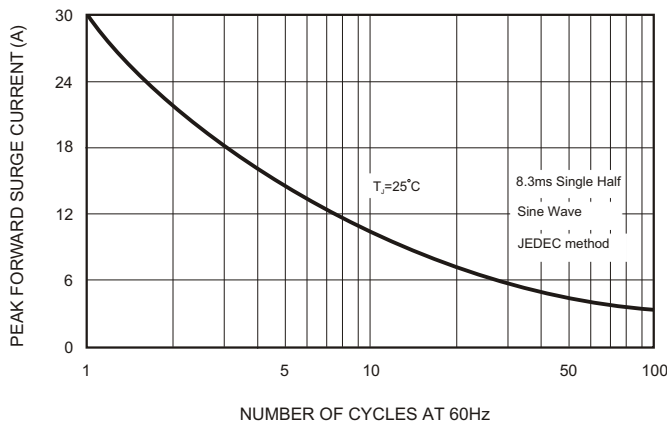


FIG.4 TYPICAL JUNCTION CAPACITANCE

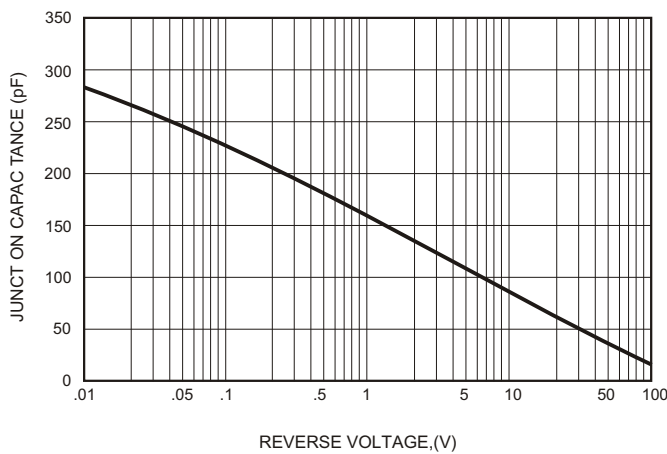


FIG.5 TYPICAL REVERSE CHARACTERISTICS

